VS-SD300N/R Series

Vishay Semiconductors

Standard Recovery Diodes, (Stud Version), 380 A



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DO-9 (DO-205AB)

380 A

DO-9 (DO-205AB)

Single

PRIMARY CHARACTERISTICS

I_{F(AV)}

Package

Circuit configuration

FEATURES

- Wide current range
- High voltage ratings up to 3200 V
- · High surge current capabilities
- · Stud cathode and stud anode version
- Standard JEDEC[®] types
- Compression bonded encapsulations
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

- Converters
- Power supplies
- · Machine tool controls
- High power drives
- Medium traction applications

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VS-SD	UNITS	
PARAIVIETER	TEST CONDITIONS	16 to 20	25 to 32	
1		380	380	A
I _{F(AV)}	T _C	100	70	°C
I _{F(RMS)}		595	425	
1	50 Hz	6050	6050	А
IFSM	60 Hz	6335	6335	
l ² t	50 Hz	183	183	kA ² s
1-1	60 Hz	167	167	KA-S
V _{RRM}	Range	1600 to 2000	2500 to 3200	V
TJ		-40 to +180	-40 to +150	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$I_{RRM} MAXIMUM AT T_J = T_J MAXIMUM mA$
	16	1600	1700	
	20	2000	2100	
VS-SD300N/R	25	2500	2600	15
	28	2800	2900	
	32	3200	3300	

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FORWARD CONDUCTION							
DADAMETED		TEST CONDITIONS		SD300N/R			
PARAMETER	SYMBOL			16 to 20	25 to 32	UNITS	
	I _{F(AV)}				380	270	А
Maximum average forward current		190° conduction half size wave		100	100	°C	
at case temperature			180° conduction, half sine wave		300	380	А
				125	70	°C	
Maximum RMS forward current	I _{F(RMS)}	DC at T _C =	88 °C (02 to 24	4), T _C = 91 °C (25 to 32)	595	425	
		t = 10 ms	No voltage	Sinusoidal half wave, initial T _J = T _J maximum	6050		
Maximum peak, one-cycle forward,	I =0.1	t = 8.3 ms	reapplied		6335		A
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		5090		
		t = 8.3 ms	reapplied		5330		
	l ² t	t = 10 ms	No voltage		183		kA ² s
Maximum I ² t for fusing		t = 8.3 ms	reapplied		167		
Maximum r r for fusing	11	t = 10 ms	100 % V _{RRM}		129		
		t = 8.3 ms	reapplied		118		
Maximum I ² √t for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied		18	30	kA²√s	
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		0.95		v	
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)}), T_J = T_J maximum$		1.05			
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$), T _J = T _J maximum		0.75		mΩ	
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J maximum$		$(I > \pi \times I_{F(AV)}), T_J = T_J$ maximum 0.66		66	
Maximum forward voltage drop	V_{FM}	$I_{pk} = 1180 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sinusoidal wave}$		1.83	1.83	v	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER SYMBOL		TEST CONDITIONS	SD300N/R		UNITS
	TEST CONDITIONS	16 to 20	25 to 32		
Maximum junction operating temperature range	TJ		-40 to 180	-40 to 150	°C
Maximum storage temperature range	T _{Stg}		-55 to 200		1
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.11		K/W
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat, and greased 0.04		04	r∨ vv
Maximum allowed mounting torque ± 10 %		Not-lubricated threads 27		7	Nm
Approximate weight			25	50	g
Case style		See dimensions (link at the end of datasheet)	DO-9	9 (DO-205A	B)

CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.019	0.013			
120°	0.023	0.023			
90°	0.028	0.030	$T_J = T_J maximum$	K/W	
60°	0.042	0.044			
30°	0.073	0.074			

Note

The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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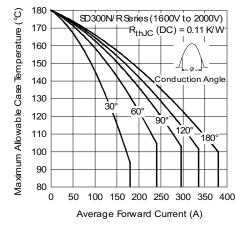


Fig. 1 - Current Ratings Characteristics

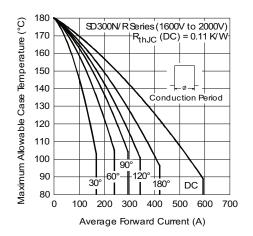


Fig. 2 - Current Ratings Characteristics



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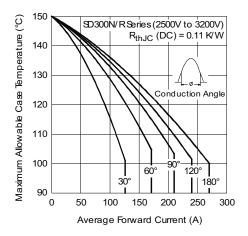


Fig. 3 - Current Ratings Characteristics

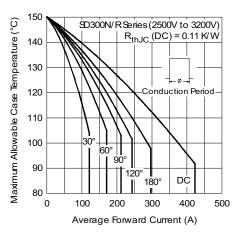
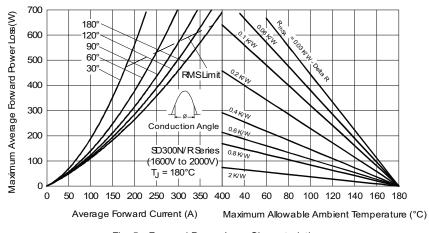


Fig. 4 - Current Ratings Characteristics





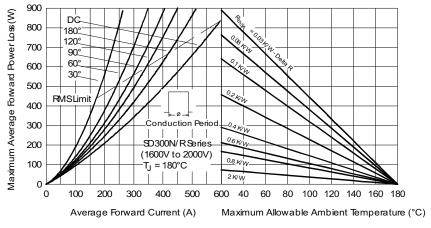
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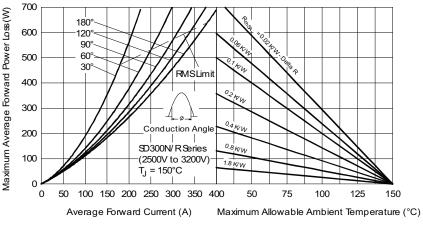
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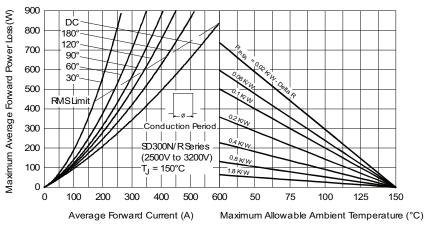


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Fig. 6 - Forward Power Loss Characteristics





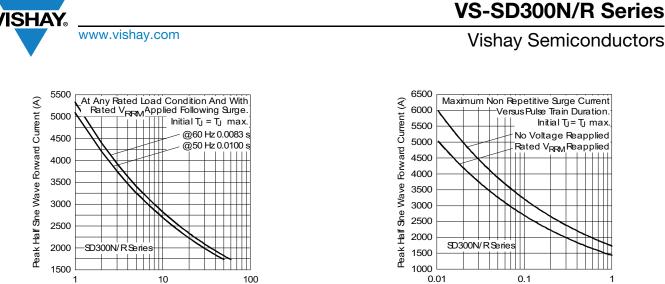




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Number Of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 9 - Maximum Non-Repetitive Surge Current

1

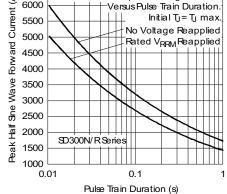


Fig. 10 - Maximum Non-Repetitive Surge Current

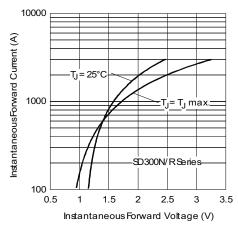


Fig. 11 - Forward Voltage Drop Characteristics

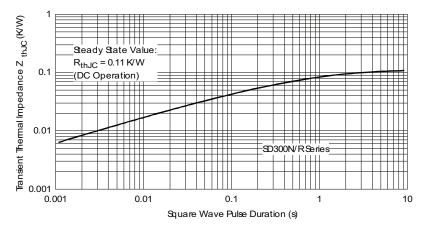


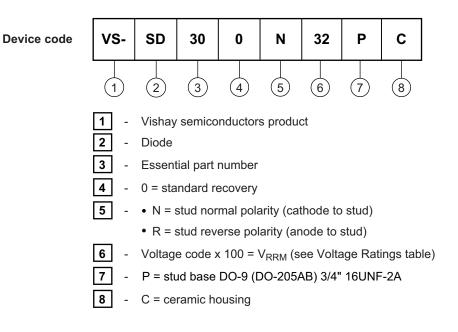
Fig. 12 - Thermal Impedance ZthJC Characteristics



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ORDERING INFORMATION TABLE



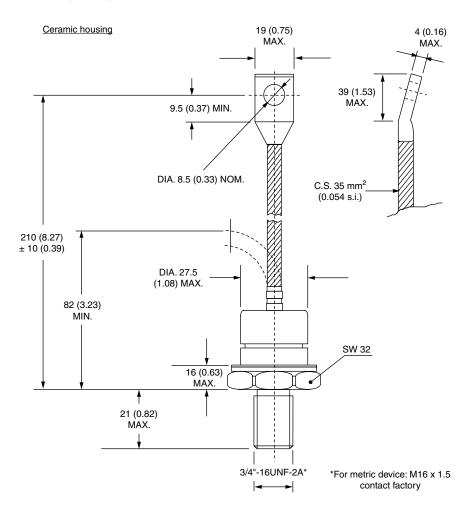
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95301		

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DO-205AB (DO-9)

DIMENSIONS in millimeters (inches)





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